

PS25401A / B

EPIC Ultra High Impedance Movement Sensor



Data Sheet 291837 issue 2

FEATURES

- Ultra high effective input resistance, typically 20GΩ.
- Effective input capacitance as low as 15pF.
- Upper 3dB point typically 10kHz.
- Operates with bipolar power supply from $\pm 2.4V$ to $\pm 4.0V$.
- Sensors supplied in a custom package with exposed pins for surface mount assembly.

APPLICATIONS

- Proximity switching of lighting and similar electric circuits
- Remote control of TVs and other domestic appliances
- Presence detection for security / alarm systems
- Room occupancy detection for rescue services
- Simple gesture recognition to control children's toys
- Controller-less computer gaming systems

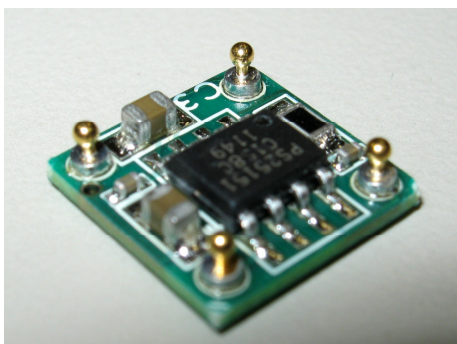
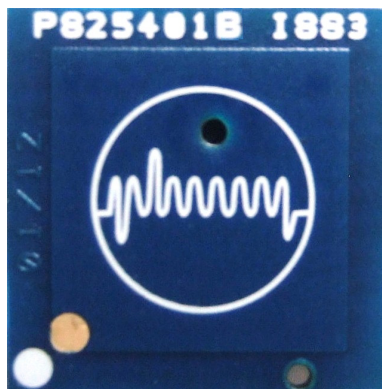


Fig. 1 The PS25401B Sensor

Ordering Information

PS25401B
Custom package

-25°C to +75°C

Plessey Semiconductors Electric Potential Integrated Circuit (EPIC) product line targets a range of applications.

The PS25401B is an ultra high impedance non-contact solid state electric potential sensor. It can be used to detect field disturbance due to the movement of a near-by object. This functionality can be employed in a range of applications including security motion sensors and non-contact electric switches for lighting, door opening, toys etc

The device uses active feedback techniques to both lower the effective input capacitance of the sensing element (C_{in}) and boost the input resistance (R_{in}). These techniques are used to realise a sensor with a frequency response suitable for remote sensing applications.

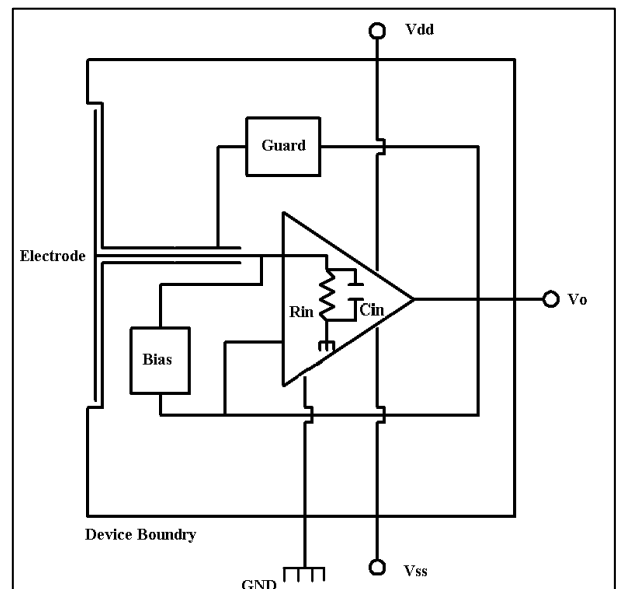


Fig. 2 Internal circuit of EPIC Movement Sensor

ELECTRICAL CHARACTERISTICS

$T_{amb} = -25^{\circ}\text{C}$ to $+75^{\circ}\text{C}$, $V_{dd}/V_{ss} \pm 2.4\text{V}$ to $\pm 4.0\text{V}$. The electrical characteristics are guaranteed by either production test or by design and characterisation. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

Characteristics	Value			Units	Conditions
	Min.	Typ.	Max.		
Supply voltage	± 2.4		± 4.0	V	Bipolar supply, Gnd=0V
Supply current	1.5	2.5	3.5	mA	
Effective input resistance		20		G Ω	
Effective input capacitance		15		pF	As measured at the sensor electrode
Voltage Gain (Av)		50			When measured with 250pF coupling capacitance
Lower -3dB point		0.20		Hz	Set by internal DC signal rejection network – coupling capacitor 250pF
Upper -3dB point		10.0		kHz	
Noise		tbd			

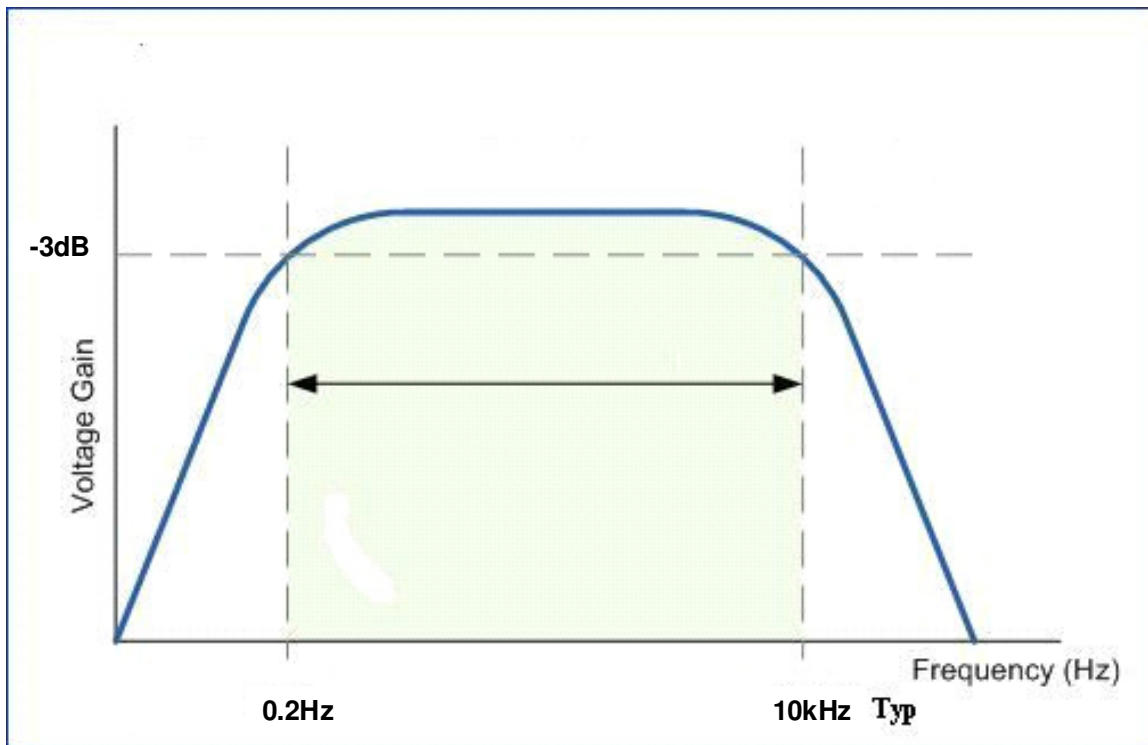


Fig. 3 Typical Bode Plot for PS25401B Sensor with Coupling through 250pF Capacitor

PIN ASSIGNMENT

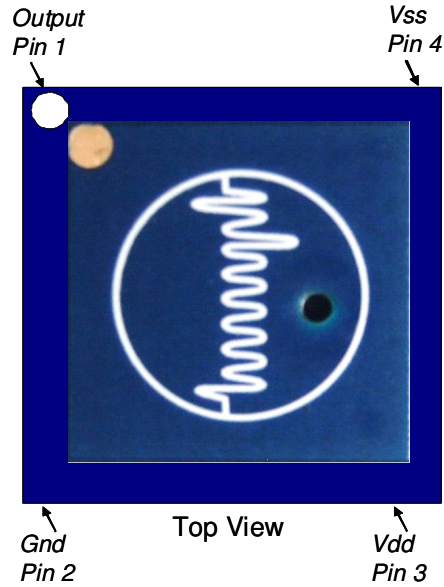


Fig. 4 Pin Assignment for the PS25401B – Top View

MECHANICAL DIMENSIONS

The package diagram is shown below. It is recommended that a solder pad 1.6mm diameter be defined for the mounting of the sensor pins.

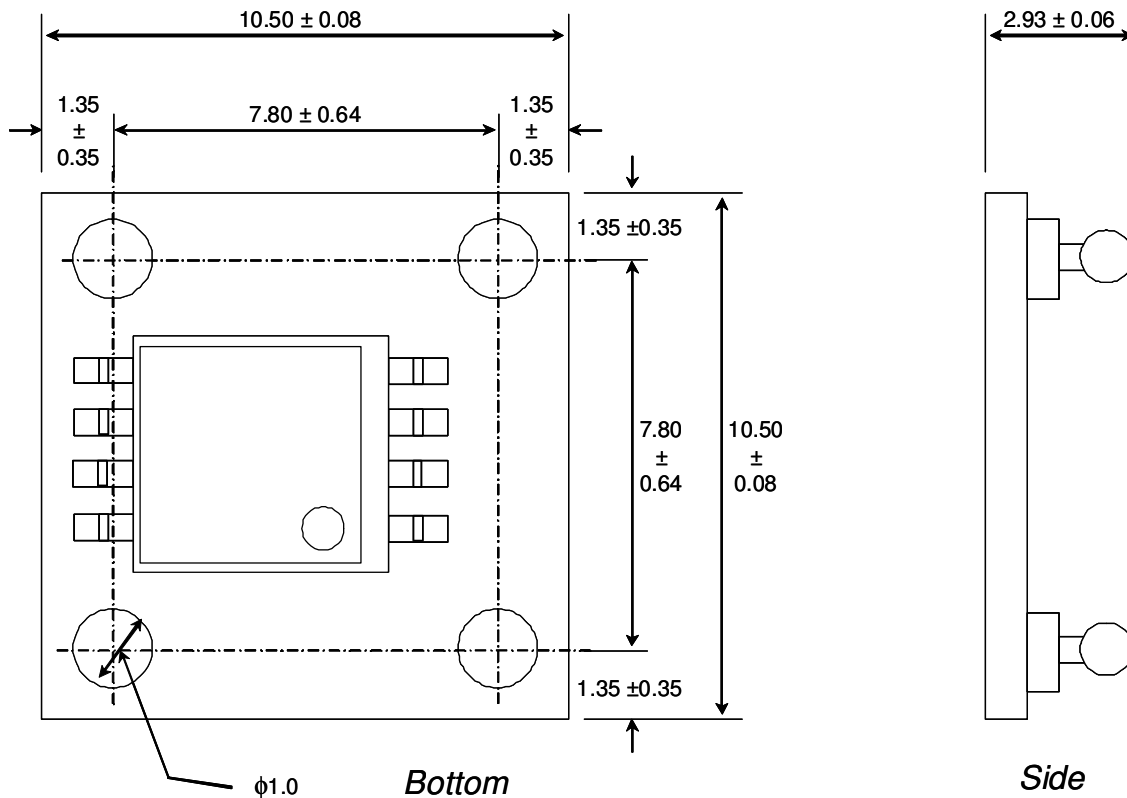


Fig. 5 Mechanical Drawing (all dimensions are nominal and in mm)

ELECTROSTATIC DISCHARGE (ESD) PROTECTION

The PS25401B is manufactured using a high performance analog CMOS process. As for all CMOS components, it is essential that conventional ESD protection protocols be applied for the handling of this device.

PATENTS

This component and many of the associated applications are covered by the following international patents:

602 32 911.6-08 (DE)	EP2174416
AU2007228660	GB1118970.1
CA2646411	JP2009-500908
CN200780026584.8	JP4391823
EP1451595 (CH)	TW097126903
EP1451595 (ES)	TW1308066
EP1451595 (FR)	US12/293872
EP1451595 (IE)	US12/374359
EP1451595 (IT)	US12/669615
EP1451595 (NL)	US13/020890
EP2002273	US13/163988
EP2047284	US7885700



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